## ENSC 388

## Assignment \#7

Assignment date: Wednesday Nov. 04, 2009
Due date: Wednesday Nov. 11, 2009

## Problem 1

A thin silicon chip and an 8 -mm-thick aluminum substrate are separated by a $0.02-$ mm thick epoxy joint. The chip and substrate are each 10 mm on a side, and their exposed surfaces are cooled by air, which is at a temperature of $25^{\circ} \mathrm{C}$ and provides a convection coefficient of $100 \mathrm{~W} / \mathrm{m}^{2} \cdot \mathrm{~K}$. If the chip dissipates $104 \mathrm{~W} / \mathrm{m}^{2}$ under normal conditions, will it operate below a maximum allowable temperature of $85^{\circ} \mathrm{C}$ ?
Note: the thermal resistant at the interface between the silicon chip and the aluminum plate with 0.02-mm epoxy is: $R_{t, c}=0.9 \times 10^{-4} \mathrm{~m}^{2} \mathrm{~K} / \mathrm{W}$


## Problem 2

Consider a long solid tube, insulated at the outer radius $r_{2}$ and cooled at the inner radius $r$ ), with uniform heat generation $\dot{q}\left(W / \mathrm{m}^{3}\right)$ within the solid.

1. Obtain the general solution for the temperature distribution in the tube.
2. In a practical application a limit would be placed on the maximum temperature that is permissible at the insulated surface $\left(r=r_{2}\right)$. Specifying this limit as $T_{s, 2}$ identify appropriate boundary conditions that could be used to determine the arbitrary constants appearing in the general solution. Determine these constants and the corresponding form of the temperature distribution.
3. Determine the heat removal rate per unit length of tube.
4. If the coolant is available at a temperature $T_{\infty}$, obtain an expression for the convection coefficient that would have to be maintained at the inner surface to allow for operation at prescribed values of $T_{s, 2}$ and $\dot{q}$.

Note: conduction heat transfer with generation in cylindrical coordinate is:

$$
\frac{1}{\mathrm{r}} \frac{1}{\mathrm{dr}}\left(\mathrm{r} \frac{\mathrm{dT}}{\mathrm{dr}}\right)+\frac{\dot{\mathrm{q}}}{\mathrm{k}}=0
$$



## Problem 1:

Known:
Dimensions, heat dissipation, and maximum allowable temperature of a silicon chip. Thickness of aluminum substrate and epoxy joint. Convection conditions at exposed chip and substrate surfaces.

## Find:

- Whether maximum allowable temperature is exceeded.


## Assumptions:

1. Steady-state conditions.
2. One-dimensional conduction (negligible heat transfer from sides of composite).
3. Negligible chip thermal resistance (an isothermal chip).
4. Constant properties.
5. Negligible radiation exchange with surroundings.

## Properties:

Pure aluminum ( $T \sim 350 \mathrm{~K}$ ): $k=239 \mathrm{~W} / \mathrm{m} \cdot \mathrm{K}$ (Table A-24).

## Analysis:

Heat dissipated in the chip is transferred to the air directly from the exposed surface and indirectly through the joint and substrate. Performing an energy balance on a control surface about the chip, it follows that, on the basis of a unit surface area,

$$
q_{c}^{\prime \prime}=q_{1}^{\prime \prime}+q_{2}^{\prime \prime}
$$

Or

$$
q_{c}^{\prime \prime}=\frac{T_{c}-T_{\infty}}{(1 / h)}+\frac{T_{c}-T_{\infty}}{R_{t, c}^{\prime \prime}+(L / k)+(1 / h)}
$$

To conservatively estimate $T c$, the maximum possible value of $R_{t, c}^{\prime \prime}=0.9 \times 10^{-4}$
$\mathrm{m}^{2} \cdot \mathrm{~K} / \mathrm{W}$ is obtained from Table. Hence

$$
T_{c}=T_{\infty+} q_{c}^{\prime \prime}\left[h+\frac{1}{R_{t, c}^{\prime \prime}+(L / k)+(1 / h)}\right]^{-1}
$$

Or

$$
\begin{gathered}
T_{c}=25^{\circ} \mathrm{C}+\frac{10^{4} \mathrm{~W}}{m^{2}} \times\left[100+\frac{1}{(0.9+0.34+100) \times 10^{-4}}\right]^{-1} \mathrm{~m}^{2} . \mathrm{K} / \mathrm{W} \\
T_{c}=25^{\circ} \mathrm{C}+50.3^{\circ} \mathrm{C}=75.3^{\circ} \mathrm{C}
\end{gathered}
$$

Hence the chip will operate below its maximum allowable temperature.

## Problem 2:

## Known:

Solid tube with uniform heat generation IS insulated at the outer surface and cooled at the inner surface.

Find:

1. General solution for the temperature distribution $T(r)$.
2. Appropriate boundary conditions and the corresponding form of the temperature distribution.
3. Heat removal rate for specified maximum temperature.
4. Corresponding required convection coefficient at the inner surface.

## Assumptions:

1. Steady-state conditions.
2. One-dimensional radial conduction.
3. Constant properties.
4. Uniform volumetric heat generation.
5. Outer surface adiabatic.

## Analysis:

To determine $T(r)$, the appropriate form of the heat equation, the equation of heat transfer in cylindrical coordinate must be solved. For the prescribed conditions, this expression reduces to equation:

$$
\begin{equation*}
\frac{1}{r} \frac{1}{d r}\left(r \frac{d T}{d r}\right)+\frac{\dot{q}}{k}=0 \tag{1}
\end{equation*}
$$

and the general solution is given by:

$$
\begin{equation*}
T(r)=-\frac{\dot{q}}{4 k} r^{2}+C_{1} \ln r+C_{2} \tag{2}
\end{equation*}
$$

Hence, this solution applies in a cylindrical shell, as well as in a solid cylinder. Two boundary conditions are needed to evaluate $C_{1}$ and $C_{2}$, and in this problem it is appropriate to specify both conditions at $r_{2}$. Invoking the prescribed temperature limit,

$$
\begin{equation*}
T\left(r_{2}\right)=T_{s, 2} \tag{3}
\end{equation*}
$$

and applying Fourier's law, at the adiabatic outer surface

$$
\begin{equation*}
\left.\frac{d T}{d r}\right|_{r_{2}}=0 \tag{4}
\end{equation*}
$$

Using Equations (2) and (3), it follows that

$$
\begin{equation*}
T_{s, 2}=-\frac{\dot{q}}{4 k} r_{2}^{2}+C_{1} \ln r_{2}+C_{2} \tag{5}
\end{equation*}
$$

Similarly, from Equations (4) and (1):

$$
\begin{equation*}
0=-\frac{\dot{q}}{2 k} r^{2}+C_{1} \tag{6}
\end{equation*}
$$

Hence

$$
\begin{equation*}
C_{1}=\frac{\dot{q}}{2 k} r^{2} \tag{7}
\end{equation*}
$$

and from Equation (3)

$$
\begin{equation*}
C_{2}=T_{s, 2}+\frac{\dot{q}}{4 k} r_{2}^{2}-\frac{\dot{q}}{2 k} r_{2}^{2} \ln r_{2} \tag{8}
\end{equation*}
$$

Substituting Equations (7) and (8) into the general solution, Equation (2), it follows that

$$
\begin{equation*}
T(r)=-\frac{\dot{q}}{2 k} r_{2}^{2} \ln \frac{r_{2}}{r}+\frac{\dot{q}}{4 k}\left(r_{2}^{2}-r^{2}\right)+T_{s, 2} \tag{9}
\end{equation*}
$$

The heat removal rate may be determined by obtaining the conduction rate at $r_{1}$ or by evaluating the total generation rate for the tube. From Fourier's law

$$
\begin{equation*}
q_{r}^{\prime}=-k 2 \pi r \frac{d T}{d r} \tag{10}
\end{equation*}
$$

Hence, substituting from Equation (9) and evaluating the result at $r_{1}$,

$$
\begin{align*}
& q_{r}^{\prime}\left(r_{1}\right)=-k 2 \pi r_{1}\left(-\frac{\dot{q}}{2 k} r_{1}+\frac{\dot{q}}{2 k} \frac{r_{2}^{2}}{r_{1}}\right)  \tag{11}\\
& =-\pi \dot{q}\left(r_{2}^{2}-r_{1}^{2}\right)
\end{align*}
$$

Alternatively, because the tube is insulated at $r_{2}$ the rate at which heat is generated in the tube must equal the rate of removal at $r_{1}$. That is, for a control volume about the tube, the energy conservation requirement, reduces to $\dot{E_{g}}-E_{\text {out }}=0$, where $\dot{E_{g}}=\pi \dot{q}\left(r_{2}^{2}-r_{1}^{2}\right) L$ and $E_{\text {out }}^{\dot{\prime}}=q_{\text {cond }}^{\prime} L=-q_{r}^{\prime}\left(r_{1}\right) L$. Hence

$$
\begin{equation*}
q_{r}^{\prime}\left(r_{1}\right)=-\pi \dot{q}\left(r_{2}^{2}-r_{1}^{2}\right) \tag{13}
\end{equation*}
$$

Applying the energy conservation requirement, to the inner surface, it follows that ,

$$
\begin{align*}
& \quad q_{c o n d}^{\prime}=q_{c o n v}^{\prime}  \tag{14}\\
& \text { Or } \\
& \quad \pi \dot{q}\left(r_{2}^{2}-r_{1}^{2}\right)=h 2 \pi r_{1}\left(T_{s, 1}-T_{\infty}\right) \tag{15}
\end{align*}
$$

Hence

$$
\begin{equation*}
h=\frac{\dot{q}\left(r_{2}^{2}-r_{1}^{2}\right)}{2 r_{1}\left(T_{s, 1}-T_{\infty}\right)} \tag{16}
\end{equation*}
$$

where $T_{s, 1}$ may be obtained by evaluating Equation (10) at $r=r_{1}$.

